

Search History (7 pp) # (5/24/05)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2853	((327/534) or (327/535) or (327/536) or (327/537) or (257/299) or (257/901)).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/05/24 11:26
L2	8	L1 and charge adj pump and substrate near3 bias and "p-type" near2 substrate and "n-well" near4 bias and (switch switching)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/24 11:28
S1	5	"712523".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 11:37
S2	5	"712523".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:52
S3	10	integrated adj circuit near3 switch. clm. and integrated adj circuit near3 switch.ti. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:54
S4	11	integrated adj circuit near3 switch. ab,clm. and integrated adj circuit near3 switch.ti. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:58
S5	585	spst adj switch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:58
S6	74	spst adj switch.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:58
S7	0	spst adj switch.ti,ab,clm. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 09:59
S8	11	spst adj switch and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:03

S9	5	spst adj switch near10 (cmos cmosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:46
S10	10	cmos adj switch.ti,ab,clm. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:04
S11	11	cmos adj switch.ti,ab,clm. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:38
S12	17	comfet.ti,ab,clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:08
S13	0	regenerative adj switch near4 (mosfet cmos cmosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:30
S14	0	regenerative adj switch near4 spst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:30
S15	0	regenarive adj switch and spst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:38
S16	0	regenerative adj switch and spst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:42
S17	663	regenerative near10 (single spst)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:43
S18	0	regenerative near4 spst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:53

S19	0	regenerative near10 spst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:44
S20	0	spst adj switch near10 (cmos cmosfet) and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:52
S21	0	spst adj switch.ti,ab,clm. and "257"/\$9.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/24 10:52
S22	15	(cmos cmosfet).ti,ab,clm. and switch near4 substrate near4 potential	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/24 10:54
S23	5	"712523".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 12:01
S24	50	(spdt single-pole adj double-throw) adj switch.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 13:05
S25	5	(spdt single-pole adj double-throw) adj switch.ti. and (spdt single-pole adj double-throw) adj switch.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 13:12
S26	0	(spdt single-pole adj double-throw) adj switch.ti. and 257/109.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 14:15
S27	20	regenerative adj2 switch.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 13:21
S28	130	spdt adj switch and (cmosfet cmos nfet pfet nmosfet pmosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 13:22

S29	5	(US-20040022025-\$ or US-20030222704-\$ or US-20030042567-\$).did. or (US-6836172-\$ or US-5818099-\$). did.	US-PGPUB; USPAT	OR	OFF	2005/02/11 13:41
S30	54	(257/548).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 13:42
S31	0	(spdt single-pole adj double-throw) adj switch and 257/109.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 14:15
S32	144	257/109.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/11 14:18
S33	130	(257/299).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 14:18
S34	2	S33 and variable near6 bias and low near3 voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 14:19
S35	60	S33 and low near3 (voltage potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/11 15:11
S36	8	(US-20040022025-\$ or US-20030222704-\$ or US-20030042567-\$).did. or (US-6836172-\$ or US-5818099-\$ or US-5488247-\$ or US-6303957-\$ or US-6218895-\$).did.	US-PGPUB; USPAT	OR	OFF	2005/02/11 15:41
S37	5	"712523".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 11:52
S38	1076	spdt adj switch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 12:19

S39	3	spdt adj switch and substrate and (cmos cmosfet) and charge adj pump\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 12:20
S40	3	spdt adj switch and substrate and (cmos cmosfet) and charge adj pump\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:22
S41	20	(single adj pole adj double adj throw spdt) adj switch and substrate and charge adj pump\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:25
S42	9	(single adj pole adj double adj throw spdt) adj switch and substrate and charge adj pump\$3 near6 switch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:29
S43	4	(single adj pole adj double adj throw spdt) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:31
S44	2	(single adj pole adj double adj throw spdt) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking) and SPDT	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:32
S45	4	(single adj pole adj double adj throw) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:45
S46	4	(single adj pole adj double adj throw) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking) and (grnd ground grounded)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 13:01
S47	4	(single adj pole adj double adj throw) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking) and (grnd ground grounded) and (input output)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 13:56

S48	1	(single adj pole adj double adj throw) adj switch and substrate and charge adj pump\$3 near6 switch\$3 and current near4 (leak leakage leaking) and (grnd ground grounded) and (input output) and substrate near4 (potential voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 13:16
S49	1	switch near6 regulate near4 substrate near1 potential	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 13:57
S50	6	switch near6 (regulating regulate) near4 substrate near1 (bias voltage potential)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 14:22
S51	136	(257/299).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 14:27
S52	1	S51 and (switch\$3 near6 (bias biasing) near6 ground)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 16:24
S53	103	(cmos cmosfet).ti,ab,clm. and plurality near3 wells	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 17:10
S54	1	(cmos cmosfet).ti,ab,clm. and plurality near3 wells and nakazato. in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/23 17:10
S55	11	(US-20030042567-\$ or US-20030151877-\$ or US-20030222704-\$ or US-20040022025-\$).did. or (US-4798974-\$ or US-5386135-\$ or US-5488247-\$ or US-5818099-\$ or US-6218895-\$ or US-6303957-\$ or US-6836172-\$).did.	US-PGPUB; USPAT	OR	OFF	2005/05/24 08:13
S56	141	(257/901).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/24 08:33

S57	3	S56 and (switch switching) and charge adj (pump pumping enabl\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/24 09:13
S58	595	(327/534).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/24 09:13
S59	28	S58 and substrate near2 bias\$3 near20 switch\$3 and charge adj pump\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/24 09:14
S60	23	S58 and substrate: near2 bias\$3 near20 switch\$3 and charge adj pump\$3 and (cmos cmosfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/24 11:26